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ANISOTROPY OF UPPER CRITICAL FIELD NEAR TC AND MAGNETIC GAP OF SUPERCONDUCTING URu2Si2 SINGLE CRYSTAL.

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Studying thermal conductivity and STM spectra in the normal and magnetic phase of superconducting URu₂Si₂ single crystal, we found, that the magnetic gap, partially opened on the Fermi surface below Neel temperature $T_N = 17.5$ K, is strongly anisotropic: gapped states mainly correspond to tetragonal ab plane.

At present, strongly correlated superconducting electron systems, including HTSC and heavy fermion superconductors are intensively investigated. The main purpose of our work was to study anisotropy of the magnetic gap in the superconducting URu,Si, single crystal at T>T from dependences temperature of thermal conductivity and STM spectra to compare their character with symmetry properties of the upper critical field H_{c2} near T_c .

The measurements were performed on a single crystal about 1*1*5 mm³, oriented along c-axis . En T_=1.16K¹. Temperature dependences of thermal conductivity, electrical resistivity and Seebeck of URu,Si, single crystal coefficient along the c-axis are shown in Fig.1. that below T_{μ} : k= AT+ BT³+ Assuming Δ /T), the k values being A_exp(determined by electron, phonon and, magnon contributions respectively and neglecting the change in electron part k. $(k_{a} < (1/10)k$, see insert on Fig.1), then extrapolating $k=AT+BT^3$ dependence from $T=T_N$ to T=0 and substracting these values

from experimantal data, we may estimate magnetic gap along c-axis $\Delta \approx 54$ K.

Fig.2 presents typical anisotropy of dynamical conductivity, dI/dV at T=2K. For tip direction along at plane a strong anomaly in dI/dV near zero bias





voltage due to gap in the DOS is observed. Depending on tip position and separation between tip and surface, the value of the gap varies up to 20 meV. For tunneling spectra along tetragonal axis- only a small asymmetric feature near V=0 in the dI/dV curves was seen (Fig.2,insert).

In URu₂Si₂, below T_u spin waves with moment transfer and polarization vector along ordered moment² coexist with gapping of at least half of FS, obtained from heat capacity³. Discrepancy between gap value, estimated from heat transport along c-axis $\Delta \approx 54$ K and from heat capacity ($\Delta \sim$ 150K) may originate from the strong anisotropy of magnetic gap. While for magnetic excitations along caxis only a spin wave gap of 1.8 meV is formed², calculations of FS in ab plane show gapping spectrum of in Adirections and relatively high DOS in B-points⁴ (see left insert on Fig.2). Our results are in a qualitative agreement with this FS picture: for c-axis only a relatively small feature in dI/dV characteristics near V=0 is seen, but along ab-plane strong anomalies in dI/dV, corresponding to gap at Fermi level up to 20 meV are observed.

Anisotropy of the $H_{c2}(T_c)$ studied at the same crystal¹, did not reveal 4-fold symmetry in the basal plane, possibly due to the small mean free path. Nevertheless, strong reduction of the H_{c2} in the c-direction in comparison with ab-plane¹, may also reflect symmetry of FS: for \vec{H} II \vec{c} electrons are rotating in the ab-plane and crossing regions of gapped DOS, while for \vec{H} II ab-plane the probability of such intersections is much less.



Fig.2 Dynamic conductivity dI/dV along ab-plane for various tip-sample distances (solid lines) and along c-axis (dashed-dotted lines) at T=2K. Left insert demonstrates calculated in⁴ FS picture in the ab-plane.

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